



### 0.5A SBR SURFACE MOUNT SUPER BARRIER RECTIFIER

### Product Summary (@ T<sub>A</sub> = +25°C)

V <sub>RRM</sub> (V)	I <sub>O</sub> (mA)	V <sub>F</sub> Max (V)	I <sub>R</sub> Max (μA)
20	500	0.5	50

#### **Features and Benefits**

- Ultra-Low Forward Voltage Drop
- Superior Reverse Avalanche Capability
- Patented Super Barrier Rectifier Technology
- Soft, Fast Switching Capability
- +150°C Operating Junction Temperature
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2) Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

### **Applications**

- **SMPS**
- DC-DC Converter
- Freewheeling Diodes
- Reverse Polarity Protection

#### **Mechanical Data**

- Case: X2-DFN1006-2
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish NiPdAu over Copper Leadframe. Solderable per MIL-STD-202, Method 208 @4
- Weight: 0.001 grams (Approximate)

X2-DFN1006-2



**Bottom View** 

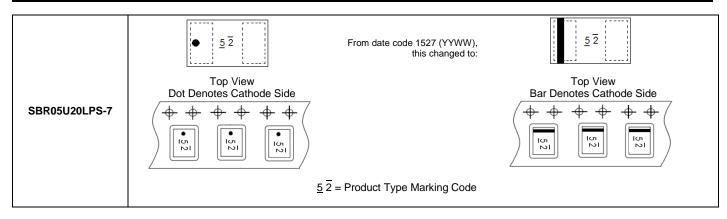
### Ordering Information (Note 4)

Part Number	Case	Packaging
SBR05U20LPS-7	X2-DFN1006-2	3,000/Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

## **Marking Information**





# **Maximum Ratings** (@T<sub>A</sub> = +25°C unless otherwise specified.)

Single phase, half wave, 60Hz, resistive or inductive load. For capacitance load, derate current by 20%.

Characteristic	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>RM</sub>	20	٧
RMS Reverse Voltage	V <sub>R(RMS)</sub>	14	V
Average Rectified Output Current (See Figure 1)	Io	500	mA
Non-Repetitive Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on Rated Load	I <sub>FSM</sub>	6	А

## **Thermal Characteristics**

Characteristic	Symbol	Value	Unit
Maximum Thermal Resistance (Note 5)	$R_{\theta JA}$	224	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-65 to +150	°C

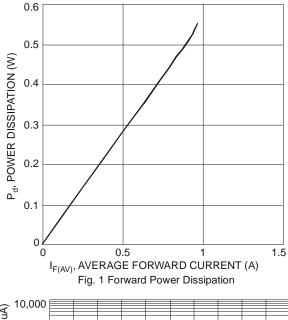
# **Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

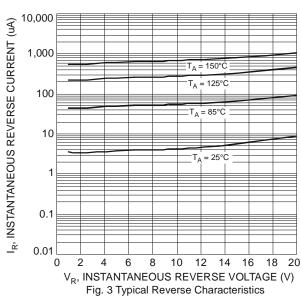
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Reverse Breakdown Voltage (Note 6)	V <sub>(BR)R</sub>	20		ı	V	I <sub>R</sub> = 50μA
Forward Voltage Drop	VF	ı	0.34 0.25 0.38 0.31 0.47 0.42	0.38 0.28 0.42 0.34 0.50 0.45	V	I <sub>F</sub> = 0.1A, T <sub>J</sub> = +25°C I <sub>F</sub> = 0.1A, T <sub>J</sub> = +150°C I <sub>F</sub> = 0.2A, T <sub>J</sub> = +25°C I <sub>F</sub> = 0.2A, T <sub>J</sub> = +150°C I <sub>F</sub> = 0.5A, T <sub>J</sub> = +25°C I <sub>F</sub> = 0.5A, T <sub>J</sub> = +150°C
Leakage Current (Note 6)	I <sub>R</sub>	-	6 1.5	50 5	μA mA	$V_R = 20V, T_J = +25$ °C $V_R = 20V, T_J = +150$ °C

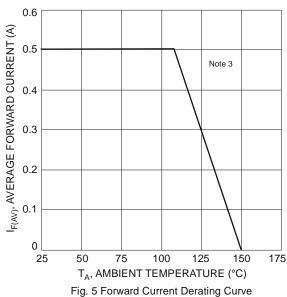
Notes:

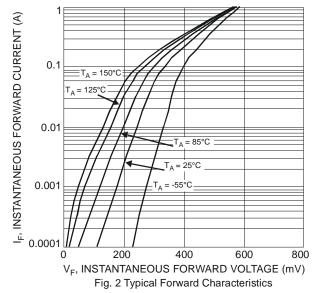
<sup>5.</sup> Device mounted on FR-4 substrate. 2" x 2" 2oz. Copper, single sided PCB board. 6. Short duration pulse test used to minimize self-heating effect.











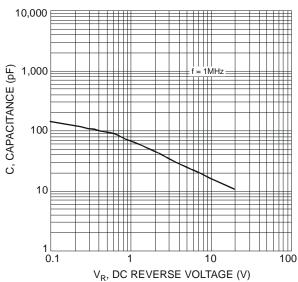


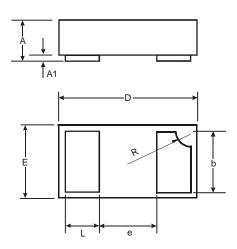
Fig. 4 Total Capacitance vs. Reverse Voltage 150 T<sub>A</sub>, DERATED AMBIENT TEMPERATURE (°C) 125 100 75 50 25 0 2 10 12 14 0 8 V<sub>R</sub>, DC REVERSE VOLTAGE (V)



# **Package Outline Dimensions**

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.

#### X2-DFN1006-2

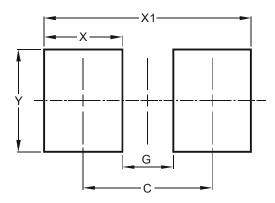


X2-DFN1006-2					
Dim	Min	Max	Тур		
Α	0.34	0.4	0.37		
A1	0	0.05	0.03		
b	0.45	0.55	0.50		
D	0.95	1.075	1.00		
Е	0.55	0.675	0.60		
е	_	_	0.40		
L	0.20	0.30	0.25		
R	0.05	0.15	0.10		
All Dimensions in mm					

# **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.

#### X2-DFN1006-2



Dimensions	Value (in mm)
C	0.70
G	0.30
Х	0.40
X1	1.10
Y	0.70



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